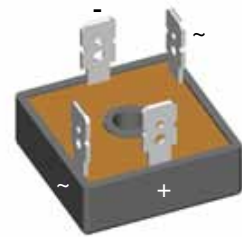
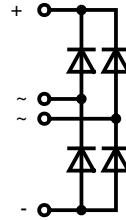


# Single Phase Rectifier Bridge

$$I_{dAV} = 21 \text{ A}$$

$$V_{RRM} = 800-1800 \text{ V}$$

| $V_{RSM}$<br>V | $V_{RRM}$<br>V | Type         |
|----------------|----------------|--------------|
| 900            | 800            | VBO 22-08NO8 |
| 1300           | 1200           | VBO 22-12NO8 |
| 1700           | 1600           | VBO 22-16NO8 |
| 1900           | 1800           | VBO 22-18NO8 |



| Symbol     | Conditions  | Maximum Ratings |                  |
|------------|---|-----------------|------------------|
| $I_{dAV}$  | $T_C = 85^\circ\text{C}$ , module                         | 17              | A                |
| $I_{dAVM}$ | $T_C = 63^\circ\text{C}$ , module                         | 21              | A                |
| $I_{FSM}$  | $T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz) | 380             | A                |
|            | $V_R = 0$ ; $t = 8.3 \text{ ms}$ (60 Hz)                  | 440             | A                |
|            | $T_{VJ} = T_{VJM}$ ; $t = 10 \text{ ms}$ (50 Hz)          | 360             | A                |
|            | $V_R = 0$ ; $t = 8.3 \text{ ms}$ (60 Hz)                  | 400             | A                |
| $I^2t$     | $T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz) | 725             | A <sup>2</sup> s |
|            | $V_R = 0$ ; $t = 8.3 \text{ ms}$ (60 Hz)                  | 800             | A <sup>2</sup> s |
|            | $T_{VJ} = T_{VJM}$ ; $t = 10 \text{ ms}$ (50 Hz)          | 650             | A <sup>2</sup> s |
|            | $V_R = 0$ ; $t = 8.3 \text{ ms}$ (60 Hz)                  | 650             | A <sup>2</sup> s |
| $T_{VJ}$   |   | -40...+150      | °C               |
| $T_{VJM}$  |   | 150             | °C               |
| $T_{stg}$  |   | -40...+150      | °C               |
| $V_{ISOL}$ | 50/60 Hz, RMS $t = 1 \text{ min}$                         | 2500            | V~               |
|            | $I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$            | 3000            | V~               |
| $M_d$      | Mounting torque (M5)<br>(10-32 UNF)                       | 2 ±10%          | Nm               |
|            |   | 18 ±10%         | lb.in.           |
| Weight     | Typ.  | 22              | g                |

## Features

- Package with ¼" fast-on terminals
- Isolation voltage 3000 V~
- Planar passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered E 72873

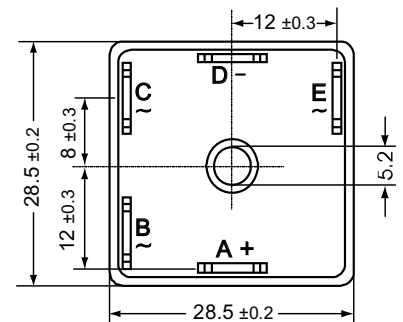
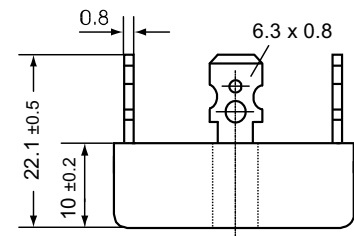
## Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature & power cycling

## Dimensions in mm (1 mm = 0.0394")



| Symbol     | Conditions  | Characteristic Values |                  |
|------------|---|-----------------------|------------------|
| $I_R$      | $V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$       | 0.3                   | mA               |
|            |   | 5.0                   | mA               |
| $V_F$      | $I_F = 150 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$ | 2.2                   | V                |
| $V_{T0}$   | For power-loss calculations only                  | 0.85                  | V                |
| $r_t$      |   | 12                    | mΩ               |
| $R_{thJC}$ | per diode; 120° el.                               | 8.20                  | K/W              |
|            | per module  | 2.05                  | K/W              |
| $R_{thJH}$ | per diode; 120° el.                               | 9.40                  | K/W              |
|            | per module  | 2.35                  | K/W              |
| $d_s$      | Creeping distance on surface                      | 12.7                  | mm               |
| $d_A$      | Creepage distance in air                          | 9.4                   | mm               |
| $a$        | Max. allowable acceleration                       | 50                    | m/s <sup>2</sup> |

Data according to IEC 60747 and refer to a single diode unless otherwise stated.

IXYS reserves the right to change limits, test conditions and dimensions.

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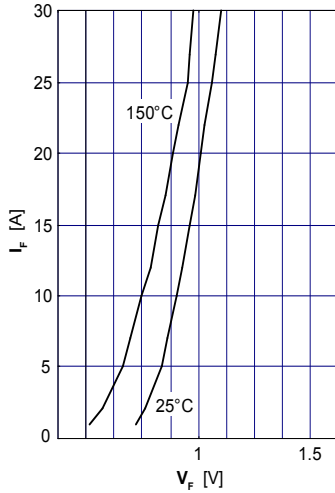


Fig. 1 Forward current versus voltage drop per diode

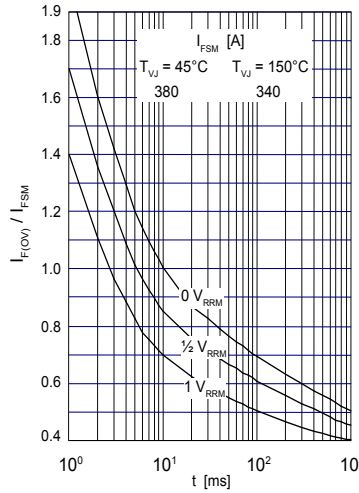


Fig. 2 Surge overload current per diode  
I<sub>FSM</sub>: Crest value. t: duration

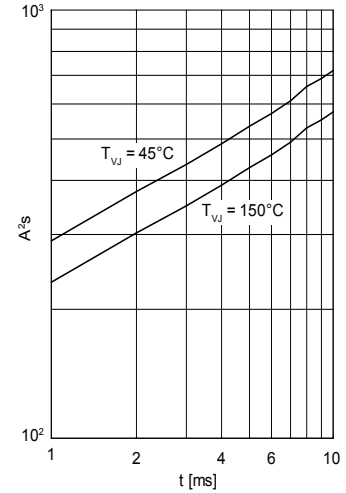


Fig. 3 I<sup>2</sup>t versus time (1-10 ms) per diode or thyristor

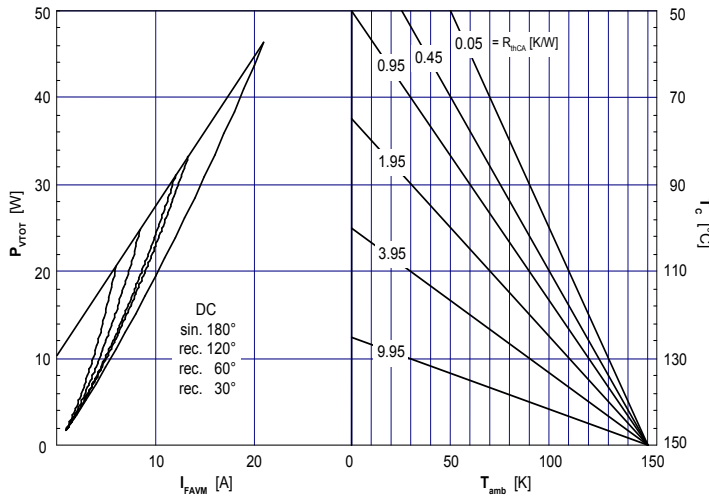


Fig. 4 Power dissipation vs. direct output current and ambient temperature

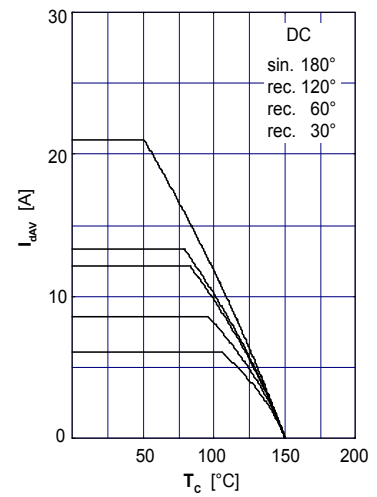


Fig. 5 Maximum forward current at case temperature

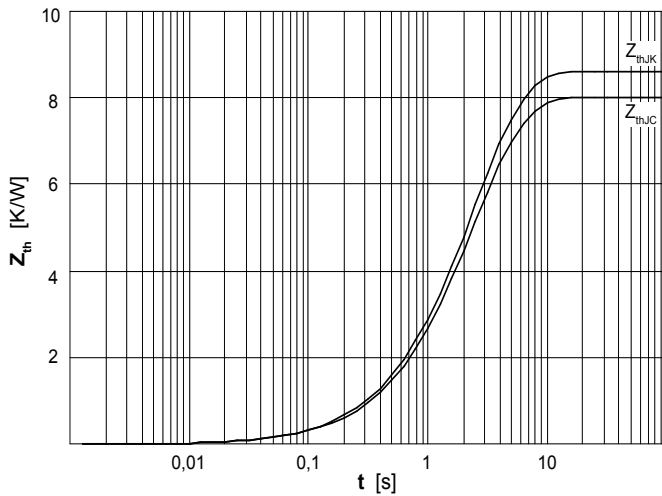


Fig. 6 Transient thermal impedance per diode or thyristor, calculated

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